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PVA–FeCl₃ composites as substrate and packaging materials for the controlled degradation of non-degradable metals in transient electronics†

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Progress in transient electronics depends largely on the availability of components and materials that can decompose in aqueous solutions. However, some of the most important electrically conductive materials, such as copper or aluminum, do not fall into this category. Here, we report a concept for solving this problem based on the preparation of a new water-soluble polymer composite as a packaging material that, when dissolved, releases a chemical etchant that decomposes these two metals. We investigate the synthesis, chemical properties, and solubility kinetics of a polyvinyl alcohol–iron chloride (PVA–FeCl₃) composite, its degradation properties, and the associated dissolution mechanisms of metallic Al and Cu films and traces. The results show that Cu films dissolve in a rapid and uniform fashion and produce copper(I) chloride as the end product, while Al films exhibit inconsistent dissolution behavior. Moreover, the timescale for complete dissolution of Cu and Al can be adjusted by simply varying the amount of FeCl₃ in the composite. The distinct advantages of this triggered transience mode include low cost, simplicity, precise control of the dissolution process by varying the polymer composition, and a universal degradation mechanism that can be extended to numerous transient electronic devices.

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10th Anniversary Statement

As a doctoral student (M. N.), the predecessor journal, *Journal of Materials Chemistry*, was an important companion to my research, and my first article in that journal not only made me incredibly proud, but gave me the feeling of belonging to the scientific community. This did not change after the *Journal of Materials Chemistry* was split into three sister journals 10 years ago: the *Journal of Materials Chemistry A* remains one of the leading journals in the field of materials chemistry, and even now as a laboratory head I am delighted when a paper of ours is accepted for publication there. Although I sometimes miss the days when you could go to the library every week to read the thin issues of the few relevant scientific journals, I am pleased that the *Journal of Materials Chemistry A* has maintained its commitment to the highest quality even as the number of articles has increased significantly.

1. Introduction

We, as a human society, are addicted to electronic devices, which are continuously being equipped with new features to expand their potential applications. The most recent addition is

the “transience” nature, wherein devices are built with an expiry date.¹ These devices operate for a well-defined time and then harmlessly disintegrate into their surroundings in a controlled fashion when exposed to external stimuli.² Transient electronics have broad potential applications, including biomedical devices, environmental monitoring, military, and homeland security, to name a few.³

The design and development of physically transient materials and components are crucial for further progressing the field of transient electronics and their applications. So far, many types of transient materials have been explored, including biodegradable and bioresorbable metals,⁴ metal oxides and nitrides,⁵ stimuli-responsive polymers,⁶ and nanomaterials.⁷ For most of these materials, transience has been tailored for aqueous conditions involving chemical dissolution or physical disintegration due to the dissolution of the underlying substrate. For such reaction environments, the choice of

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materials for the manufacture of transient electronics is highly limited. Many materials such as copper (Cu), nickel (Ni), gold (Au) and aluminum (Al), which are indispensable in conventional electronics due to their excellent electrical conductivity, are excluded because of their insolubility in water. Clearly, a gap exists here, and hence a strategy that can assist in degrading these non-transient metallic components can significantly widen the scope of transient electronics, especially for transient batteries.^{3,8} Ensuring complete degradation of these non-transient metals can greatly benefit the development of novel transient batteries (both primary and secondary) and taking a step further, can also drive the ultimate vision of combining transiency with recycling to achieve circular economy.^{9–11}

There are not many, but some interesting concepts on how to make non-transient metals suitable for transient electronics. Gao *et al.* developed moisture-triggered transient electronics wherein the hydrolysis process of the substrate generates corrosive organic acids that can digest various inorganic electronic materials and components.¹² Chen *et al.* investigated the dissolution chemistry and kinetics of Au in potassium ferrocyanide solution using light as the trigger source.¹³ Rogers *et al.* developed a microfluidic system using thermally expandable polymers and utilized etching chemistry to enable on-demand and complete degradation of the microfluidic system.¹⁴ Yu *et al.* adopted the same concept of using chemical etchants for the on-demand degradation of transient electronics, but instead of heat, they applied electrical current as the trigger.¹⁵ All these approaches designed to degrade non-transient electronics are novel. But still, they either involve complicated fabrication processes, require specialized materials, are device-specific, or do not allow precise control over the transience behavior of the device.

Here, we report a new design concept for substrates or packaging materials of transient electronics to generate on-demand an active chain reaction by water using ferric chloride (FeCl₃) incorporated in water-soluble polyvinyl alcohol (PVA). Upon triggering with water, the released ferric (Fe³⁺) and chloride (Cl⁻) ions readily react with non-soluble metals (*e.g.*, Cu and Al) to cause complete dissolution in a given time. Compared to other encapsulation strategies, this approach has a few distinct advantages: (a) stable operation of devices until triggered by water; (b) the ability to dissolve a wide range of non-transient metals such as Cu, Al, Ni, Mn, Sn, *etc.*, thus expanding the list of materials suitable for constructing transient electronics; (c) tunability of the degradation behavior by varying the composition of the polymer composite; and (d) facile fabrication procedure and low cost. Systematic investigations provide details of dissolution behaviors with underlying chemistries through the interaction between thin conductive metals and PVA-FeCl₃ composites. Circuit demonstration offers the potential for complex operation *via* time-dynamic dissolution in sophisticated electronic systems.

2. Results and discussion

2.1 Physico-chemical properties of PVA composite films

Polyvinyl alcohol (PVA) is a non-toxic, biocompatible, and water-soluble synthetic polymer with excellent physical and chemical

properties.¹⁶ Its superb film-forming ability, programmable water-solubility, and good dielectric properties make it a suitable substrate and packaging material for transient devices. PVA is commercially produced by the controlled alkaline hydrolysis of polyvinyl acetate, also called saponification reaction, where the ester group of polyvinyl acetate is partially replaced with the hydroxyl group.¹⁷ The length of the reaction time used for saponification determines the degree of hydrolysis of PVA, which is defined below:

$$\text{Degree of hydrolysis (\%)} = \frac{x}{x+y} \times 100$$

where x and y are the molar fractions of the hydroxyl and the acetate groups, respectively.¹⁸ The chemical structures of fully hydrolyzed and partially hydrolyzed PVA with repeating units are shown in Fig. S1.† The physico-chemical and mechanical properties of a polymer depend significantly on the degree of crystallinity, hydrolysis level, and molecular weight. For PVA, it is well documented that there is a strong inter- and intra-chain hydrogen bonding between the polar hydroxyl groups that determine its crystallinity, and thus its solubility in an aqueous solution.¹⁸ Clearly, one can tune the dissolution behavior of PVA in water by modifying the extent of hydrogen bonding between PVA chains. This can simply be done by exploring PVA with different degrees of hydrolysis and molecular weights and accordingly, the transience behavior of PVA films with molecular weights in the range of 9000–124 000 g mol⁻¹ and degrees of hydrolysis from 80% to >99% was firstly investigated.

As shown in Fig. S2,† the PVA film with 80% degree of hydrolysis dissolved more readily in water than those with degrees of hydrolysis above or close to 98%, because the increasing number of acetate groups in 80% hydrolyzed PVA disrupts its intra/inter-chain hydrogen bonding and facilitates its rapid solubility. In contrast, a very high degree of hydrolysis makes PVA more crystalline and supports stronger inter- and intra-chain hydrogen bonding, which then significantly decreases the water solubility, as indicated by the transience times of more than 60 and 600 min for 98–99% and >99% hydrolyzed PVA films, respectively. Throughout this paper, transiency is defined as the moment when the film has lost its structural integrity and degraded to an unrecognizable level. Besides the degree of hydrolysis, higher molecular weights also decrease the water-solubility of PVA films due to increased crystallinity. It is important to note that once the PVA film is submerged in water, its solubility is influenced not only by inter/intra-chain hydrogen bonding but also by the newly formed hydrogen bonds between the water molecules and PVA chains. To achieve complete dissolution of the PVA films, the hydrogen bonding between PVA chains and water molecules must dominate over the PVA–PVA chains interactions.¹⁹ Therefore, it is essential to include both kinds of hydrogen bonding when interpreting the transiency of different PVA films in water.

After obtaining fully soluble PVA films, the next step included inspecting and finding a suitable chemical trigger that can be used to degrade non-soluble metals, especially Cu and Al. As reported thus far in transient electronics, especially for transient batteries, Cu metal film has been shown to undergo



disintegration into smaller chunks due to the stresses exerted on the film from the swelling of the underlying water-soluble substrates such as sodium alginate.²⁰ On the other hand, thin Al film exhibited complete dissolution in a particular pH-controlled environment generated by the reaction between different constituent materials of the transient device.⁸ However, both these approaches are device- and materials-specific, and extending them to other transient devices using entirely different raw materials is difficult. To solve this problem and to make use of these essential yet non-transient metals, we applied the basic principles of redox chemistry and carefully incorporated a strong oxidizing agent in PVA films that can readily oxidize Cu and Al metals. However, the selection of an appropriate oxidizing agent requires the following: (a) it should be water-soluble and safe to handle; (b) it must be capable of forming stable composites with PVA; and (c) it must allow tunable degradation kinetics for both metals.

Ferric chloride (FeCl_3) is one of the most commonly used oxidizing agents and has been used to etch metals such as Cu, Al, Ni, and Sn in industrial photochemical machining.²¹ It is water-soluble and forms stable composites with PVA for applications in electrochromic, display materials, sensors, *etc.*²² In addition, FeCl_3 is widely used in wastewater treatment to remove phosphorus to prevent eutrophication,²³ thus suitable for eco-friendly, disposable, and water-soluble electronics.

PVA- FeCl_3 composite films were synthesized by mixing an appropriate amount of FeCl_3 as an additive to the aqueous polymer solution, as illustrated in Scheme S1.† The inorganic additive was found to significantly impact the dissolution behavior of PVA-based films (see Fig. 1). Based on the previous experiments, it is clear that PVA with >99% degree of hydrolysis and higher molecular weight failed to form water-soluble films; therefore, only PVA with lower molecular weights and degrees of hydrolysis were considered for these sets of experiments. Preliminary experiments using 98–99% hydrolyzed PVA with 10 and 15 wt% FeCl_3 indicated the non-soluble nature of the

composite films. Both films kept their original shape with noticeable swelling and failed to dissolve in distilled water even after 4 days, as shown in Fig. S3.† This might happen due to the increase in the degree of crystallinity of PVA films with the addition of a transition metal salt as additive. On the contrary, composite films prepared from PVA with 80% degree of hydrolysis and a much lower molecular weight fully dissolved in water within a few minutes. Surprisingly, their dissolution times were faster than that of pristine PVA films, as shown in Fig. 1.

Attenuated total reflectance Fourier transform infrared (ATR-FTIR) experiments were performed to understand the chemical modifications induced by the added FeCl_3 within the PVA polymer matrix. The ATR-FTIR spectra of pure and FeCl_3 -containing PVA films with varying additive concentrations are shown in Fig. 2a and b. The broad bands observed from 3500–3200 cm^{-1} correspond to O–H stretching from the inter/intra-chain hydrogen bonds. The vibration band between 3000–2800 cm^{-1} refers to C–H stretching from alkyl groups, and peaks between 1750–1690 cm^{-1} are due to the stretching of C=O and C–O bonds from acetate groups that are left from the partial hydrolysis of polyvinyl acetate.²⁴ The bands at 1430 cm^{-1} , 1370 cm^{-1} , and 1088 cm^{-1} correspond to O–H and C–H bending, C–H in-plane bending, and acetyl C–O stretching, respectively. For PVA- FeCl_3 composite films, the characteristic bands mainly occur in lower wavenumbers from 650–1850 cm^{-1} and show considerable frequency shifts (Fig. 2b). The intensity of the C=O stretching vibration at 1727 cm^{-1} decreases with increasing additive concentration, followed by the occurrence of a new peak at around 1710 cm^{-1} . The frequencies of C=C stretching at 1638 cm^{-1} , acetyl C–O at 1088 cm^{-1} , and skeletal vibration of PVA at 844 cm^{-1} shifts toward lower wavenumbers while the stretching frequency of acetate C–O–C at 1240 cm^{-1} has moved towards higher wavenumber.²⁵

All the observed changes in the ATR-FTIR spectra of PVA-based composite films are understood based on the chemical



Fig. 1 Digital photographs showing the time-sequential dissolution in distilled water of (a) PVA and (b) PVA-15% FeCl_3 films with M_w of 9000–10000 g mol^{-1} and 80% degree of hydrolysis.





Fig. 2 ATR-FTIR spectra of (a) PVA-FeCl₃ films with additive concentrations of 0, 1, 15, and 30 wt% and (b) enlarged spectra in the wavenumber region from 650 to 1850 cm⁻¹. (c) XRD patterns and (d) transience behavior of PVA-FeCl₃ films with different additive concentrations.

interactions between PVA and the additive, FeCl₃. Many studies have shown that the interactions between polymer and additive in composite films occur *via* an acceptor-donor mechanism.²⁶ FeCl₃ has a high spin d⁵ electron configuration, and this half-filled d-subshell is expected to have a stabilizing effect. Therefore, when this potent Lewis acid, FeCl₃, is added to a polymer, it is expected to alter the properties of the polymer through charge-transfer mechanisms such as interaction with the electron donating -OH/C=O groups of PVA to form stable complexes.²⁶ These interactions are reflected in the fluctuated intensities and wavenumbers shift of different peaks in the obtained ATR-FTIR spectra. For example, the decreasing intensity of the C=O band at 1727 cm⁻¹ points toward the attachment of Fe³⁺ to the C=O group, facilitating complex formation. In other words, FeCl₃ strongly interacts with the carbonyl group of PVA (no change in -OH peak is observed), whose total amount in the PVA matrix depends on its degree of hydrolysis. PVA used here has a degree of hydrolysis of 80% and hence contains a lot of acetate groups (-OCOCH₃) that destroy inter/intra-chain hydrogen bonding, lower crystallinity, and facilitate high water solubility. Further interaction of these carbonyl groups with Fe³⁺ leads to an even more reduced crystallinity and destruction of hydrogen bonds, resulting in an accelerated dissolution of PVA composite films in an aqueous solution. This interaction is confirmed by the affected

frequencies of the acetyl C=O group at 1638 cm⁻¹, the acetyl C-O group at 1088 cm⁻¹, and the acetate C-O-C group at 1240 cm⁻¹. The possible chemical interactions between various chemical groups of PVA and FeCl₃ is presented in Scheme S2.†

The decrease in the degree of crystallinity of the composite films with increasing additive concentration is also observed in the X-ray diffraction patterns, shown in Fig. 2c. The XRD pattern of pristine PVA film shows a broad diffraction peak centered at 2θ = 19.4°, corresponding to the (101) plane of PVA.²⁷ The presence of a broad halo and the absence of any sharp peaks indicate the semicrystalline nature of PVA. With the increased concentration of FeCl₃, the diffraction peak at ~19.4° becomes broader and shows a significant decrease in intensity. The disappearance of the (101) peak in PVA-FeCl₃ composite films indicates that the distribution of FeCl₃ as filler in the polymer matrix is random, distorting the hydrogen bonding within the polymer chains by forming charge-transfer complexes.²² Thus, both ATR-FTIR and XRD results imply that PVA-FeCl₃ composite films have even weaker inter/intra-chain hydrogen bonds than pristine PVA films and are expected to exhibit faster water-transience behavior. To confirm this, the transience of composite films was examined in distilled water, and as expected, the composite films displayed a rapid dissolution in aqueous environment. As shown in Fig. 2d, the polymer film containing the highest amount of FeCl₃ dissolved in distilled



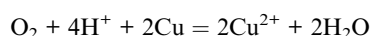
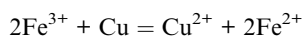
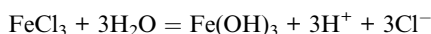
water within 150 s compared to the pure PVA films that took more than double the time (350 s) to dissolve.

These experiments clearly show that our substrates support the degradation of non-transient metals efficiently. However, they do not provide information on the long-term stability, *i.e.*, whether there are adverse effects on the conductivity of the metals during storage under ambient conditions, *e.g.*, due to accidental release of FeCl₃. These issues, which are important for the reliable operation of transient devices until their programmed decomposition, need to be investigated in future studies.

2.2 Water-triggered degradation of non-transient metals

The transience behavior and possible degradation mechanism of thin Cu film on PVA-FeCl₃ substrates are presented first. Fig. 3a and b shows the time-sequential images of Cu dissolution using 100 μm thick PVA-15% FeCl₃ as packaging material (forming top layer of the electronic) in the presence of water as a trigger. At a macroscopic level, the surface of Cu film looks rough after one minute of dissolution, followed by the development of a few micropores and then complete dissolution within two minutes. The dissolution process appears uniform, similar to that reported for metals like Mg, Mg alloys, W, and Mo.²⁸ Ferric ions are one of the most reactive oxidants and looking at the standard electrode potentials of Fe³⁺/Fe²⁺ (0.771 V), O₂/H₂O (1.229 V), and Cu²⁺/Cu (0.34 V), it is easy to conclude that thermodynamically, metallic copper can be oxidized to Cu²⁺ in the presence of Fe³⁺.²⁹ Also, molecular oxygen can accelerate the dissolution process as it acts as an oxidizing agent in the aqueous solution.

The chemical reactions resulting in the dissolution of metallic Cu films in the presence of an acidic FeCl₃ solution can be described as follows:²⁹



The acidic nature of the FeCl₃ solution resulting from the dissolution of PVA-based composite films is confirmed by the pH measurements shown in Fig. S4a.† As the dissolution progresses, the concentration of Cu²⁺ in the solution increases, and its subsequent reaction with metallic Cu also starts occurring, as shown below:



Cu⁺ is gradually consumed in other reactions, such as oxidation–reduction reactions with Fe³⁺ and H⁺ to form Cu²⁺ and complex ions like CuCl_{*n*}^(*n*-1) with the chloride anions.³⁰ These complex ions get further oxidized, releasing Cl⁻ back into the reaction mixture. The chloride anions then repeat the whole process of complexation and oxidation, and thus appear to have

an accelerating effect on the dissolution process. The presence of these complex ions is confirmed by grazing incidence angle XRD studies conducted on the Cu film before and after the dissolution process. The grazing incidence angle XRD patterns in Fig. S4b† show the characteristic peak at 2θ = 47.5°, corresponding to the (220) crystal plane of copper chloride (CuCl).³¹ Hence, FeCl₃ functions as both an oxidant and a complexing agent during the dissolution process of the metallic Cu film.

Next, the reaction kinetics of the Cu dissolution process were studied using composite films integrated with an in-house-built electronic device that contained three different colored light-emitting diodes (LEDs) connected in parallel with thin Cu traces (see Fig. S5†). In the electronic circuit, a small area of the Cu trace connected to red and blue LEDs was covered/encapsulated with polymer films containing different amounts of FeCl₃, 2 and 15 wt%, respectively. These films were triggered with water in a stepwise fashion to release Fe³⁺ and Cl⁻, which initiated the dissolution process of Cu traces. As shown in Fig. 3c, the Cu trace covered with PVA-2% FeCl₃ film completely dissolved within ~25 min after the first trigger, causing the red LED to switch off. The Cu trace covered with a composite film marked as "Control" also completely dissolved, however it did not electrically affect the operation of the other LEDs. After that, the second trigger dissolved the local Cu pattern overlaid with PVA-15% FeCl₃ film in 2 minutes, which shut off the green LED, while the blue LED continued to operate due to the constant power supply through the bypass circuit. This controlled transience of metallic Cu traces using PVA-FeCl₃ films is achieved owing to the difference in the number of available reactive species (*i.e.*, Fe³⁺ and Cl⁻) and variable pH values, both processes known to accelerate the Cu dissolution process. The PVA films with lower ferric chloride concentration released a smaller number of reactive ions and provided a comparatively high pH value (~2.3, see Fig. S4a†), resulting in a slow Cu dissolution process while completely opposite happened in case of PVA-15% FeCl₃ film. This carefully designed experiment demonstrates the programmable nature of our PVA-based composite films. It also confirms that the transience time of non-transient metals (*e.g.*, Cu) is tunable by simply adjusting the additive concentration in the composite film.

The dissolution behavior of thin metallic Al films in the presence of PVA-FeCl₃ as the encapsulating layer was also studied. Fig. 4 shows the time-sequential dissolution images of a thin layer of Al (80 nm) covered with 100 μm thick PVA-15% FeCl₃ film when immersed in water. In sharp contrast to what is observed for Cu, the complete dissolution of the Al film (6 mm × 6 mm) occurred in a very slow mode over more than 2 hours. Furthermore, the optical microscopy images reveal a non-uniform dissolution process showing the occurrence of a lot of pits/cracks for Al in contrast to the uniform dissolution observed for Cu. According to the literature, chloride ion is one of the most common species that causes pitting corrosion in Al in different environments, such as seawater and the chemical industry.³² Although Al is highly resistant to various reactive agents due to a highly stable oxide layer, Cl⁻ can easily break down this passivation layer and initiate the dissolution process.



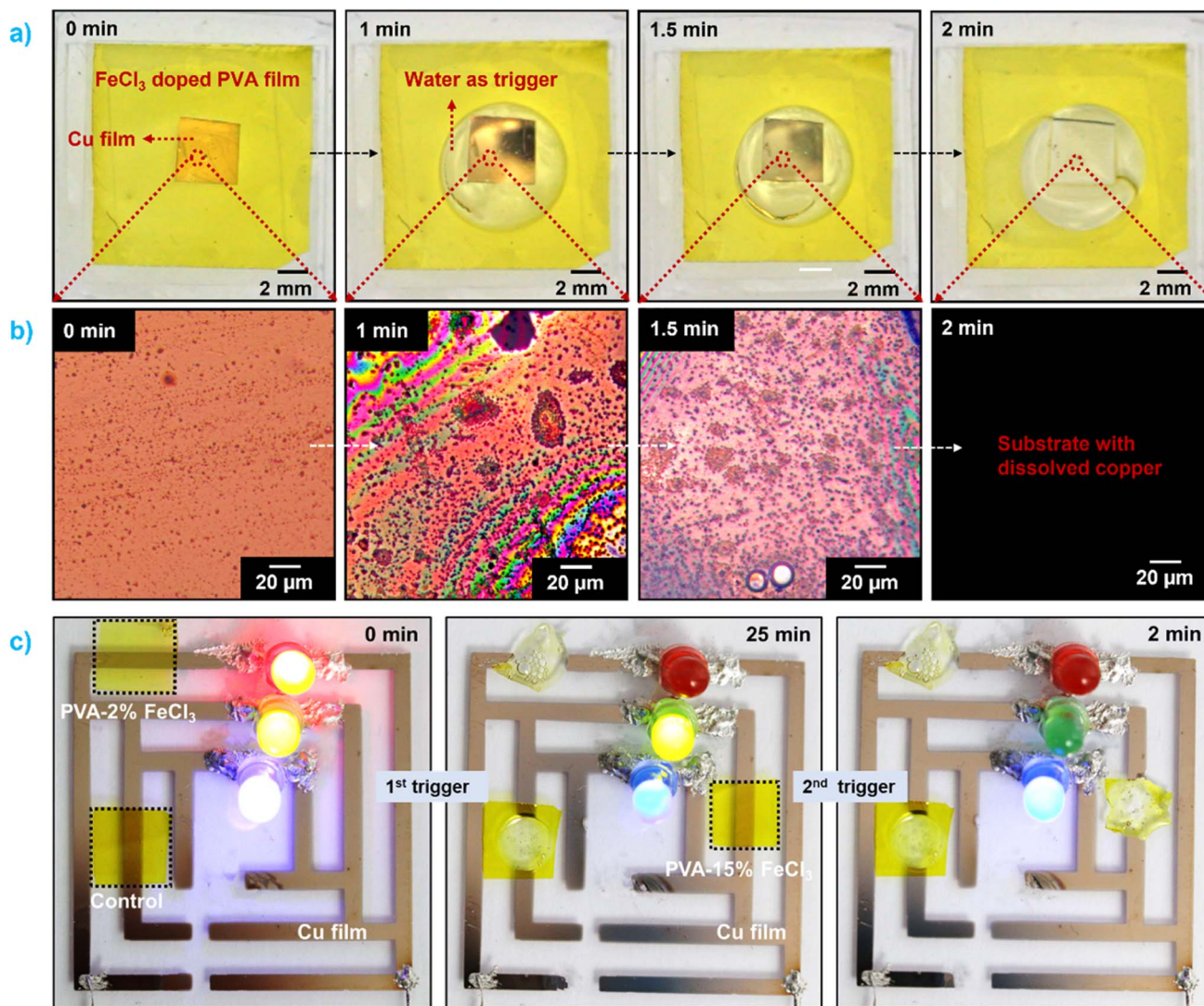


Fig. 3 Water-triggered dissolution behavior of a 100 nm thick Cu film encapsulated with PVA-15% FeCl₃ film. (a) Digital photographs and (b) optical microscopy images showing the structural changes occurring in the Cu film during dissolution. (c) Digital photographs showing the multistep degradation of Cu traces attached to LEDs by triggering PVA-FeCl₃ substrates with different additive concentrations with distilled water. The composite film marked as "control" is PVA-15% FeCl₃.

The Al dissolution process consists of four main steps described as follows. Initially, the outermost oxide layer present on the Al surface is covered with hydroxyl groups. These -OH groups will remain undissociated if the pH of the aqueous solution is the same as the isoelectric point of the oxide, which is reported to be 9.5.³³ However, in the acidic environment produced by the dissolution of the PVA-15% FeCl₃ packaging, the hydroxyl groups will get a positive charge that favors the adsorption of negatively charged Cl⁻ *via* coulombic attraction. After adsorption, these Cl⁻ penetrate through the oxide layer following several possible mechanisms, such as transport through oxygen vacancies,³⁴ water channels,³⁵ or localized film dissolution.³⁶ When Cl⁻ crosses the oxide layer and reaches the metal substrate, pitting corrosion gets initiated at the metal/oxide interface by chloride-assisted localized dissolution in the presence of water molecules as the electrolyte.³⁷ The local

dissolution of oxide film on the Al surface is called pitting. Once pitting has been initiated, it propagates on the Al surface and usually involves the formation of blisters produced by continuous localized reactions.³⁸ These blisters subsequently rupture due to the accumulation of hydrogen gas in the localized environment. The formation and rupturing of blisters were indeed observed during the water-triggered dissolution of Al film using FeCl₃ present in the composite film. The optical microscopy images showing one of those few ruptured blisters are shown in Fig. S6.† During this dissolution process, the reported degradation products are soluble aluminum complexes with chloride ions.³⁹

Besides encapsulant, PVA-FeCl₃ composite films were also utilized as substrates for transient electronics. In transient electronics, it is pretty common to deposit conductive materials, both organic and inorganic, directly on either water-soluble or biodegradable polymers to develop transient current



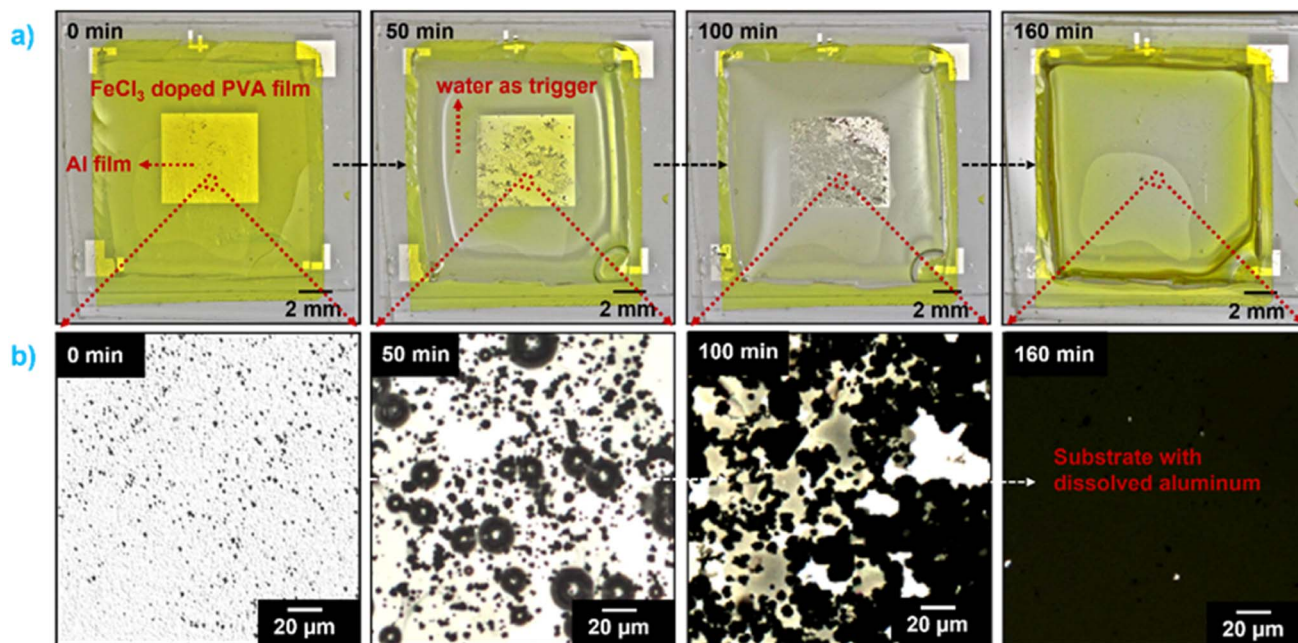


Fig. 4 Water-triggered dissolution behavior of 80 nm thick Al film encapsulated with PVA–15% FeCl_3 film. (a) Digital photographs and (b) optical microscopy images showing the structural changes occurring in the Al film during the course of dissolution.

collectors.⁴⁰ In fact, novel techniques like 3D printing have been also employed to develop transient electronics containing water soluble substrates and carbon-based conductive materials. These devices showed well controlled and preprogrammed transience behavior owing to the tunability of the structural properties of 3D-printed substrate.⁴⁰ So, we also investigated the feasibility of directly depositing Cu and Al metals on the composite films. Fig. S7† shows the free-standing PVA–15% FeCl_3 film coated with 100 nm thick Cu film in different patterns. These Cu-coated polymer composite films completely dissolved within a few minutes after triggering with water. As already described, their transiency rate can be controlled by adjusting the additive concentration or thickness of the polymer substrate. Besides transiency, it is also vital for transient substrates to present stable electrical characteristics after metal deposition, as poor electrical conductivity may result in the loss of functionality of the whole transient device. To confirm this, the electrical resistance of metallic Al film deposited on top of the PVA–15% FeCl_3 substrate was measured using a multimeter and presented in Fig. S8.† The Al film showed a low resistance value of 2.7Ω and is considered suitable to work as a substrate for numerous electronic devices. The results presented here on water-triggered transience of various conductive metals with no transient properties, such as Al and Cu, lay the solid foundation for fabricating fully soluble transient electronics.

3. Conclusion

We developed a novel transient material that can initiate the degradation of non-dissolvable metals like Al and Cu after triggering with water. The transient PVA– FeCl_3 composite decomposed these metals by chemical reactions, whose rate can be

controlled by simply varying the polymer composition. The transience time scale for both metals can be tuned over a wide range from minutes to hours and if needed, even to days. The design concept presented offers innovative options for integrating electrically conductive materials into transient electronics, thus not only expanding their application potential but also opening up space for novel developments such as transient batteries.

Conflicts of interest

There are no conflicts to declare.

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